# 74LVC1G332

# Single 3-input OR gate Rev. 4 — 6 December 2011

**Product data sheet** 

#### 1. **General description**

The 74LVC1G332 provides one 3-input OR function.

Inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of these devices as translators in mixed 3.3 V and 5 V applications.

Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall time.

This device is fully specified for partial power-down applications using I<sub>OFF</sub>. The I<sub>OFF</sub> circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

#### **Features and benefits** 2.

- Wide supply voltage range from 1.65 V to 5.5 V
- High noise immunity
- Complies with JEDEC standard:
  - ◆ JESD8-7 (1.65 V to 1.95 V)
  - ◆ JESD8-5 (2.3 V to 2.7 V)
  - ◆ JESD8B/JESD36 (2.7 V to 3.6 V)
- ESD protection:
  - ♦ HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V
  - CDM JESD22-C101-C exceeds 1000 V
- $\pm$  24 mA output drive (V<sub>CC</sub> = 3.0 V)
- CMOS low power consumption
- Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- Inputs accept voltages up to 5 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



# 3. Ordering information

Table 1. Ordering information

Type number	Package							
	Temperature range	Name	Description	Version				
74LVC1G332GW	–40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363				
74LVC1G332GV	–40 °C to +125 °C	SC-74	plastic surface-mounted package (TSOP6); 6 leads	SOT457				
74LVC1G332GM	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 $\times$ 1.45 $\times$ 0.5 mm	SOT886				
74LVC1G332GF	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 $\times$ 1 $\times$ 0.5 mm	SOT891				
74LVC1G332GN	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $0.9 \times 1.0 \times 0.35$ mm	SOT1115				
74LVC1G332GS	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 $\times$ 1.0 $\times$ 0.35 mm	SOT1202				

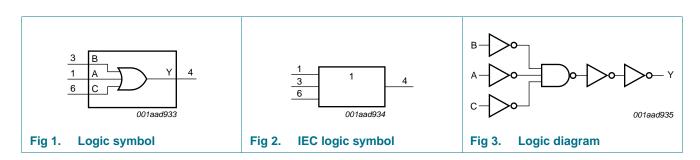
# 4. Marking

Table 2. Marking

3		
Type number	Marking code <sup>[1]</sup>	
74LVC1G332GW	YG	
74LVC1G332GV	YG	
74LVC1G332GM	YG	
74LVC1G332GF	YG	
74LVC1G332GN	YG	
74LVC1G332GS	YG	

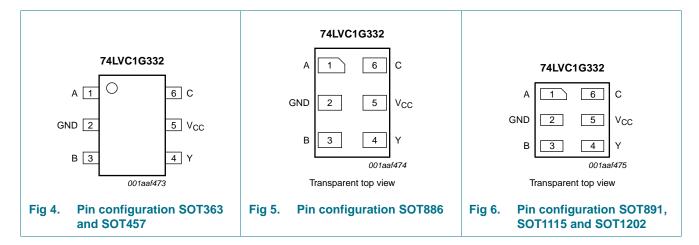
<sup>[1]</sup> The pin 1 indicator is located on the lower left corner of the device, below the marking code.

# 5. Functional diagram



# 6. Pinning information

#### 6.1 Pinning



### 6.2 Pin description

Table 3. Pin description

	••	
Symbol	Pin	Description
A	1	data input
GND	2	ground (0 V)
В	3	data input
Υ	4	data output
V <sub>CC</sub>	5	supply voltage
С	6	data input

# 7. Functional description

Table 4. Function table[1]

Input	Output		
Α	В	С	Υ
Н	X	X	Н
X	Н	X	Н
X	X	Н	Н
L	L	L	L

<sup>[1]</sup> H = HIGH voltage level;

L = LOW voltage level;

X = don't care.

# 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	+6.5	V
I <sub>IK</sub>	input clamping current	$V_I < 0 V$	-50	-	mA
VI	input voltage		<u>[1]</u> –0.5	+6.5	V
I <sub>OK</sub>	output clamping current	$V_O > V_{CC}$ or $V_O < 0 V$	-	±50	mA
Vo	output voltage	Active mode	[1][2] -0.5	$V_{CC} + 0.5$	V
		Power-down mode	[1][2] -0.5	+6.5	V
Io	output current	$V_O = 0 V \text{ to } V_{CC}$	-	±50	mA
I <sub>CC</sub>	supply current		-	100	mA
$I_{GND}$	ground current		-100	-	mA
P <sub>tot</sub>	total power dissipation	$T_{amb}$ = -40 °C to +125 °C	[3] _	250	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C

<sup>[1]</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

# 9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CC}$	supply voltage		1.65	-	5.5	V
VI	input voltage		0	-	5.5	V
Vo	output voltage	Active mode	0	-	$V_{CC}$	V
		V <sub>CC</sub> = 0 V; Power-down mode	0	-	5.5	V
T <sub>amb</sub>	ambient temperature		-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 1.65 V to 2.7 V	-	-	20	ns/V
		V <sub>CC</sub> = 2.7 V to 5.5 V	-	-	10	ns/V

<sup>[2]</sup> When  $V_{CC} = 0 \text{ V}$  (Power-down mode), the output voltage can be 5.5 V in normal operation.

<sup>[3]</sup> For SC-88 and SC-74A packages: above 87.5 °C the value of P<sub>tot</sub> derates linearly with 4.0 mW/K. For XSON6 package: above 118 °C the value of P<sub>tot</sub> derates linearly with 7.8 mW/K.

# 10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	<b>-40</b> °	-40 °C to +85 °C			-40 °C to +125 °C	
			Min	Typ[1]	Max	Min	Max	
V <sub>IH</sub>	HIGH-level	V <sub>CC</sub> = 1.65 V to 1.95 V	0.65V <sub>CC</sub>	-	-	0.65V <sub>CC</sub>	-	V
	input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7	-	-	1.7	-	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	2.0	-	-	2.0	-	V
		V <sub>CC</sub> = 4.5 V to 5.5 V	$0.7V_{CC}$	-	-	$0.7V_{CC}$	-	V
V <sub>IL</sub>	LOW-level	V <sub>CC</sub> = 1.65 V to 1.95 V	-	-	0.35V <sub>CC</sub>	-	0.35V <sub>CC</sub>	V
	input voltage	V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	-	0.7	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	-	-	8.0	-	8.0	V
		V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	$0.3V_{CC}$	-	$0.3V_{CC}$	٧
V <sub>OH</sub>	HIGH-level	$V_I = V_{IH}$ or $V_{IL}$						
	output voltage	$I_O = -100 \mu A;$ $V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}$	V <sub>CC</sub> - 0.1	-	-	V <sub>CC</sub> - 0.1	-	V
		$I_{O} = -4 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.2	-	-	0.95	-	V
		$I_{O} = -8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.9	-	-	1.7	-	V
		$I_{O} = -12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	2.2	-	-	1.9	-	V
		$I_{O} = -24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.3	-	-	2.0	-	V
		$I_{O} = -32 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.8	-	-	3.4	-	V
V <sub>OL</sub>	LOW-level	$V_I = V_{IH}$ or $V_{IL}$						
	output voltage	$I_O = 100 \mu A;$ $V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}$	-	-	0.1	-	0.1	V
		$I_O = 4 \text{ mA}; V_{CC} = 1.65 \text{ V}$	-	-	0.45	-	0.70	V
		$I_O = 8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.3	-	0.45	V
		$I_{O}$ = 12 mA; $V_{CC}$ = 2.7 V	-	-	0.4	-	0.60	V
		$I_O = 24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.55	-	0.80	V
		$I_O = 32 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.55	-	0.80	٧
l	input leakage current	$V_{CC} = 0 \text{ V to } 5.5 \text{ V};$ $V_{I} = 5.5 \text{ V or GND}$	-	±0.1	±5	-	±100	μΑ
OFF	power-off leakage current	$V_{CC} = 0 \text{ V}; V_{I} \text{ or } V_{O} = 5.5 \text{ V}$	-	±0.1	±10	-	±200	μΑ
CC	supply current	$V_{CC} = 1.65 \text{ V to } 5.5 \text{ V};$ $V_{I} = V_{CC} \text{ or GND; } I_{O} = 0 \text{ A}$	-	0.1	10	-	200	μА
7l <sup>CC</sup>	additional supply current	per pin; $V_{CC} = 2.3 \text{ V to } 5.5 \text{ V};$ $V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}$	-	5	500	-	5000	μА
Cı	input capacitance	$V_{CC} = 3.3 \text{ V}; V_I = \text{GND to}$ $V_{CC}$	-	3	-	-	-	pF

<sup>[1]</sup> All typical values are measured at  $V_{CC}$  = 3.3 V and  $T_{amb}$  = 25 °C.

# 11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for load circuit see Figure 8.

Symbol	Parameter	Conditions	-40 °C to		°C to +85	C to +85 °C		-40 °C to +125 °C	
				Min	Typ[1]	Max	Min	Max	
$t_{pd}$	propagation delay	A, B and C to Y; see Figure 7	[2]						
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		1.5	4.7	17.2	1.5	21.5	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		1.0	3.0	6.2	1.0	7.8	ns
		V <sub>CC</sub> = 2.7 V		1.0	3.0	6.0	1.0	7.5	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		1.0	2.6	4.8	1.0	6.2	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		1.0	1.9	3.5	1.0	4.4	ns
$C_{PD}$	power dissipation capacitance	$V_I = GND \text{ to } V_{CC}; V_{CC} = 3.3 \text{ V}$	[3]	-	12	-	-	-	pF

<sup>[1]</sup> Typical values are measured at  $T_{amb} = 25$  °C and  $V_{CC} = 1.8$  V, 2.5 V, 2.7 V, 3.3 V and 5.0 V respectively.

[3]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$$
 where:

 $f_i$  = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

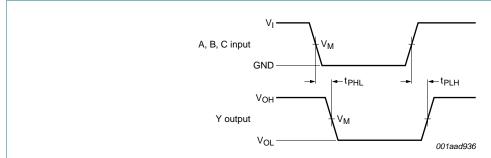
C<sub>L</sub> = output load capacitance in pF;

 $V_{CC}$  = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs.}$ 

### 12. AC waveforms



Measurement points are given in Table 9.

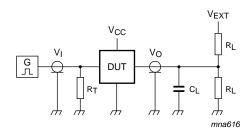
 $V_{\text{OL}}$  and  $V_{\text{OH}}$  are typical output voltage levels that occur with the output load.

Fig 7. The input A, B and C to output Y propagation delays

<sup>[2]</sup>  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

Table 9. Measurement points

Supply voltage	Input	Output
V <sub>CC</sub>	V <sub>M</sub>	V <sub>M</sub>
1.65 V to 1.95 V	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>
2.3 V to 2.7 V	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>
2.7 V	1.5 V	1.5 V
3.0 V to 3.6 V	1.5 V	1.5 V
4.5 V to 5.5 V	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>



Test data is given in Table 10.

Definitions for test circuit:

R<sub>L</sub> = Load resistance.

 $C_L$  = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance; should be equal to the output impedance  $Z_o$  of the pulse generator.

 $V_{EXT}$  = External voltage for measuring switching times.

Fig 8. Test circuit for measuring switching times

Table 10. Test data

Supply voltage	Input		Load	Load	
V <sub>CC</sub>	VI	$t_r = t_f$	CL	$R_L$	t <sub>PLH</sub> , t <sub>PHL</sub>
1.65 V to 1.95 V	$V_{CC}$	$\leq$ 2.0 ns	30 pF	1 kΩ	open
2.3 V to 2.7 V	V <sub>CC</sub>	≤ 2.0 ns	30 pF	500 Ω	open
2.7 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open
4.5 V to 5.5 V	$V_{CC}$	≤ 2.5 ns	50 pF	500 Ω	open

# 13. Package outline

#### Plastic surface-mounted package; 6 leads

**SOT363** 

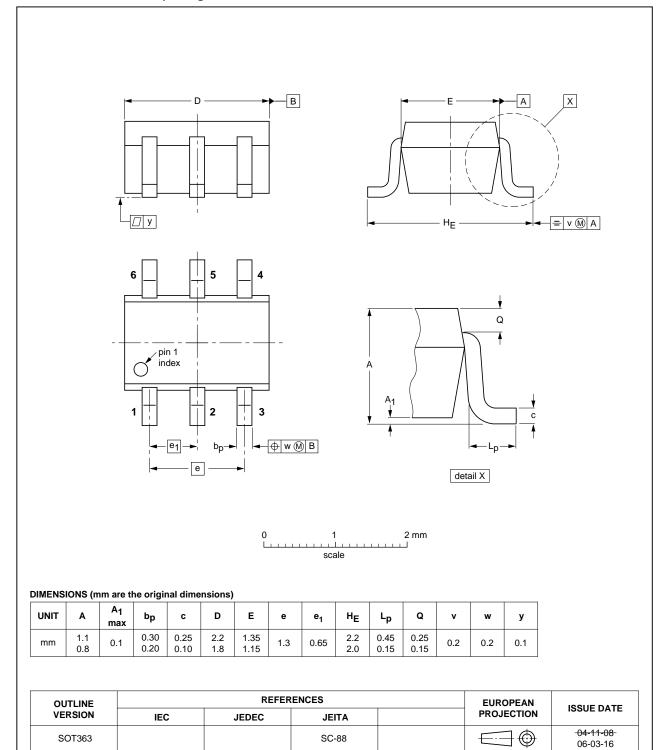


Fig 9. Package outline SOT363 (SC-88)

74LVC1G332

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#### Plastic surface-mounted package (TSOP6); 6 leads

**SOT457** 

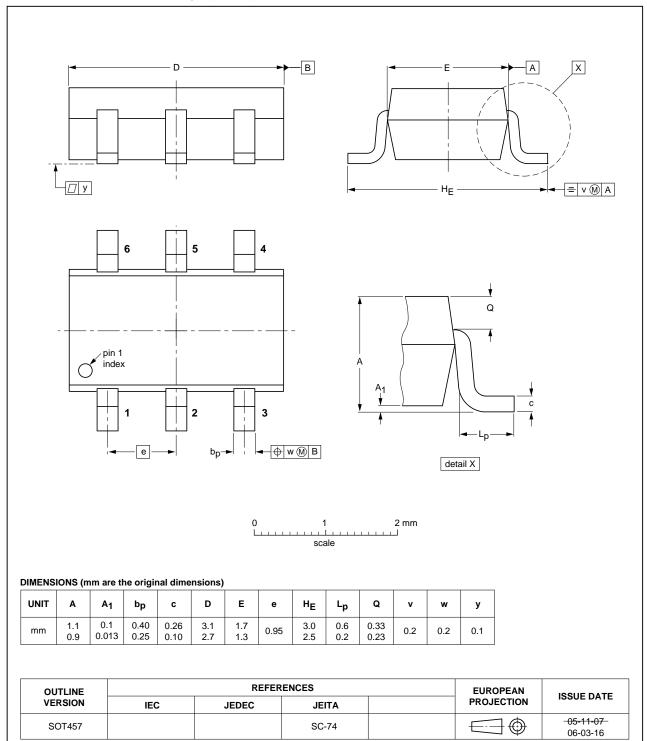


Fig 10. Package outline SOT457 (SC-74)

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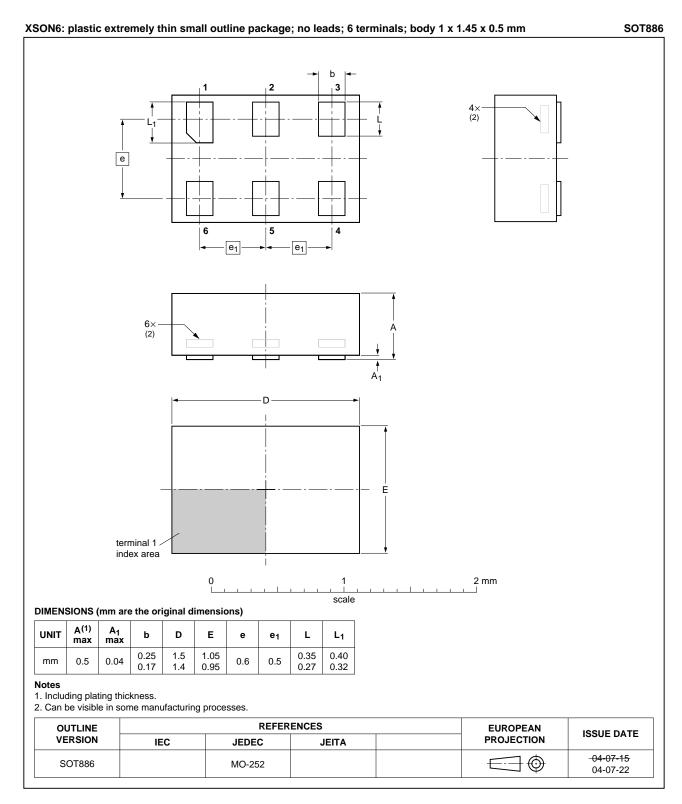


Fig 11. Package outline SOT886 (XSON6)

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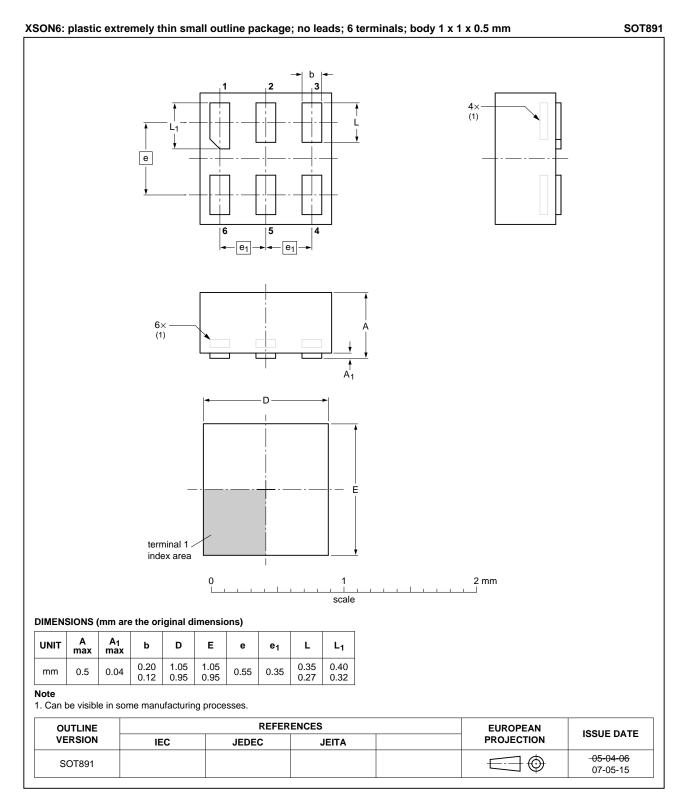


Fig 12. Package outline SOT891 (XSON6)

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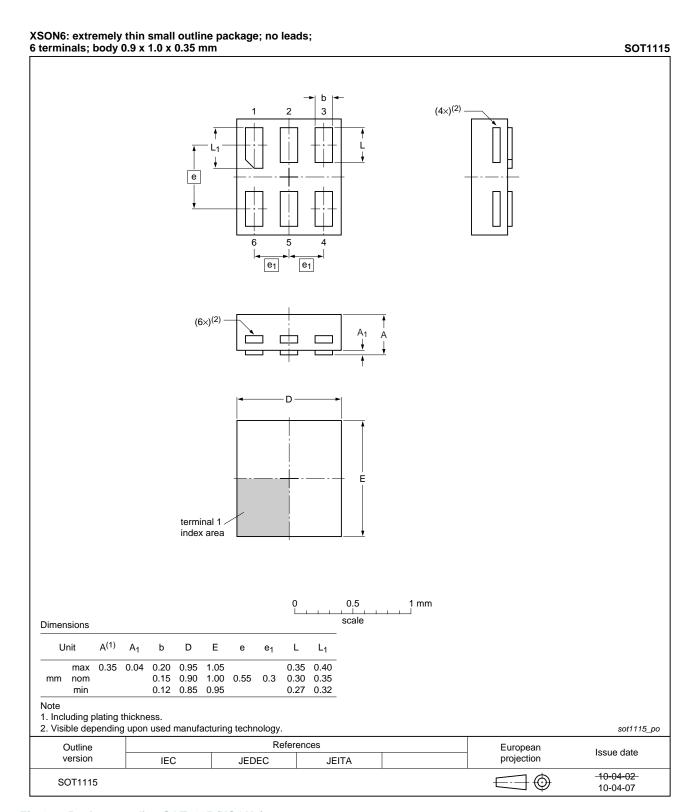


Fig 13. Package outline SOT1115 (XSON6)

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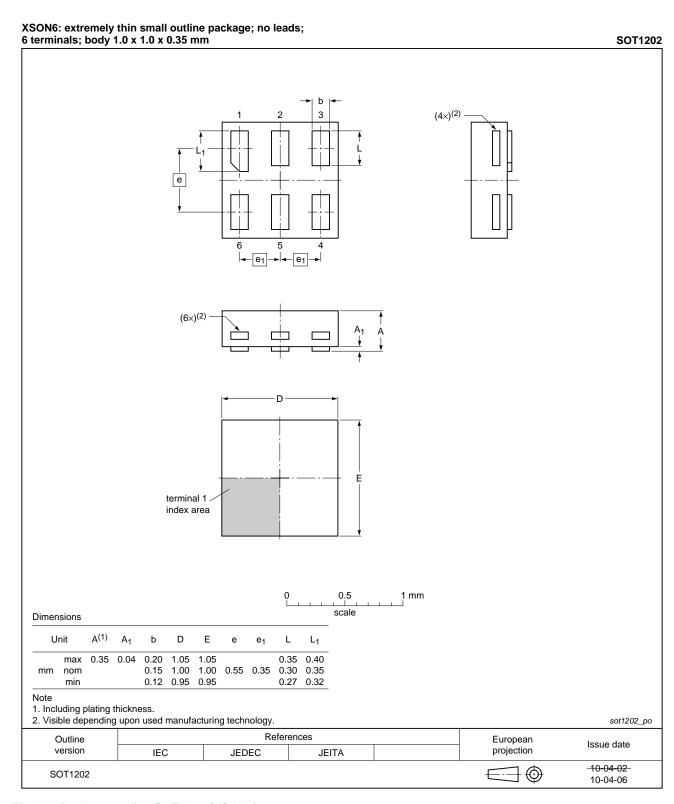


Fig 14. Package outline SOT1202 (XSON6)

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# 14. Abbreviations

#### Table 11. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

# 15. Revision history

#### Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVC1G332 v.4	20111206	Product data sheet	-	74LVC1G332 v.3
Modifications:	<ul> <li>Legal pages</li> </ul>	updated.		
74LVC1G332 v.3	20101026	Product data sheet	-	74LVC1G332 v.2
74LVC1G332 v.2	20070719	Product data sheet	-	74LVC1G332 v.1
74LVC1G332 v.1	20061011	Product data sheet	-	-

### 16. Legal information

#### 16.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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5962-8769901BCA 74HC85N NL17SG08P5T5G NL17SG32DFT2G NLU1G32AMUTCG NLV7SZ58DFT2G NLVHC1G08DFT1G
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